





# S3D50065D1 S3D50065G S3D50065H 650V SIC POWER SCHOTTKY RECTIFIERS

### **Description**

This 650V 50A diode is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D50065D1/S3D50065G/S3D50065H are ideal for energy sensitive, high frequency applications in challenging environments.

### **Applications**

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

#### **Features**

- 175°C T<sub>J</sub> operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

S3D50065D1	S3D50065G	S3D50065H
	K 2	
1 2 3		
TO-247AD	D <sup>2</sup> PAK	TO-247AC
TO-247-3	(TO-263-2)	TO-247-2
PIN 10———NC PIN 20————————————————————————————————————	PIN 1 O———————————————————————————————————	O CASE

# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	-	650	V
Average Rectified Forward Current	I <sub>F (AV)1</sub>	T <sub>C</sub> =25°C	112	Α
Average Neetined Forward Outlett	I <sub>F (AV)2</sub>	T <sub>C</sub> =137°C	50	Α
	I <sub>FRM1</sub>	10ms, Half Sine pulse, T <sub>C</sub> =25°C	121	Α
Repetitive Peak Forward Surge Current	I <sub>FRM2</sub>	10ms, Half Sine pulse, T <sub>C</sub> =110°C	68	Α
	I <sub>FSM1</sub>	10ms, Half Sine pulse, T <sub>C</sub> =25°C	300	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM2</sub>	10ms, Half Sine pulse, T <sub>C</sub> =110°C	209	Α

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### **Electrical Characteristics:**

Characteristics	Symbol	mbol Condition		Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 50A, Pulse, T <sub>J</sub> = 25 °C	1.5	1.7	V
	V <sub>F2</sub>	@ 50A, Pulse, T <sub>J</sub> = 175 °C	2.2	2.4	V
Reverse Current at DC condition*	I <sub>R1</sub>	$I_{R1}$ @V <sub>R</sub> = rated V <sub>R</sub> $I_{J} = 25 ^{\circ}\text{C}$		40	uA
Reverse Current *	$I_{R2}$		10	60	uA
Junction Capacitance	C <sub>T</sub> V <sub>R</sub> =0V, T <sub>J</sub> =25°C,f=100MHz		3120	ı	pF
Reverse Recovery Charge	Qc	$Q_c$ $I_F = 50A$ , $di/dt = 200A/\mu s$ $V_R = 400 \text{ V}$ , $T_J = 25^{\circ}\text{C}$		-	nC
Capacitance Stored Energy	E <sub>C</sub> V <sub>R</sub> = 400 V, T <sub>J</sub> =25°C		47.37	-	μJ

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	S3D50065G	S3D50065D1	S3D50065H	Units
Junction Temperature	TJ	-	-55 to +175		°C	
Storage Temperature	T <sub>stg</sub>	-	-55 to +175		°C	
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	0.75	0.70(per leg) 0.35(both leg)	0.76	°C/W

# **Ordering Information**

Device	Package	Shipping
S3D50065D1	TO-247AD(TO-247-3)	25pcs /tube
S3D50065G	D2PAK(TO-263-2)	800pcs /reel
S3D50065H	TO-247AC(TO-247-2)	25pcs /tube

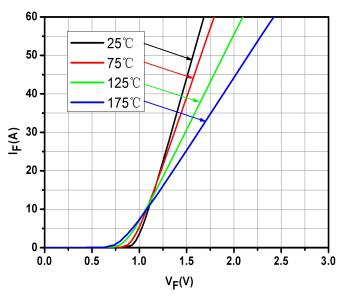
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.







# **Ratings and Characteristics Curves**

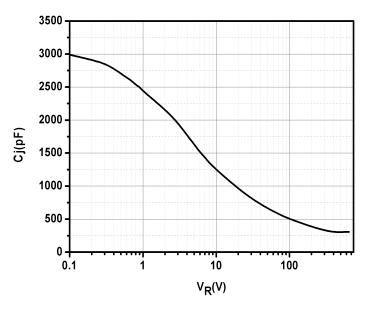


25 20 **25**℃ 75℃ IR(uA) 15 125℃ 175℃ 10 5 200 400 600 800 1000 1200 V<sub>R</sub>(V)

30

Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics



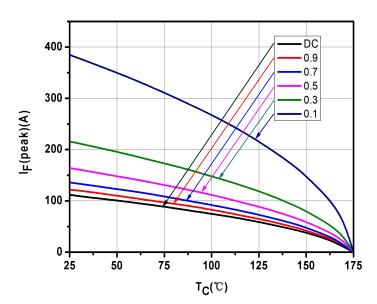


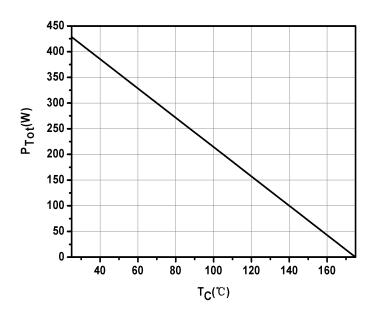
Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Current Derating









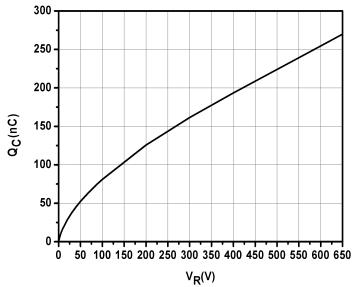


Fig.5-Power Derating

Fig.6-Total Capacitance Charge vs. Reverse Voltage

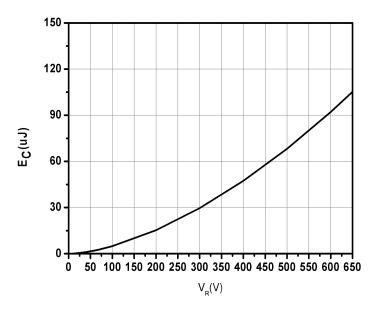


Fig.7-Capacitance Stored Energy

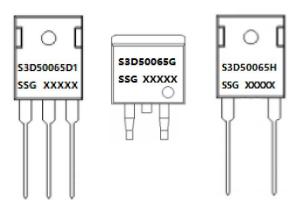
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# **Marking Diagram**



Where XXXXX is YYWWL

S3D = Device Type

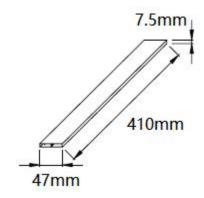
D1/G/H = Package type 50 = Forward Current (50A) = Reverse Voltage (650V) 065

SSG = SSG ΥY = Year  $\mathsf{W}\mathsf{W}$ = Week = Lot Number

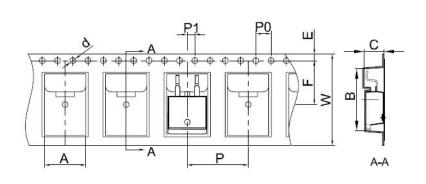
Cautions: Molding resin

Epoxy resin UL:94V-0

### **Tube Specification (TO-247-3/TO-247-2)**



# **Carrier Tape & Reel Specification**



SYMBOL	Millimeters			
STWIDOL	Min.	Max.		
Α	10.70	10.90		
В	16.03	16.23		
С	5.11	5.31		
d	1.45	1.65		
E	1.65	1.85		
F	11.40	11.60		
P0	3.90	4.10		
Р	15.90	16.10		
P1	1.90	2.10		
W	23.90	24.30		

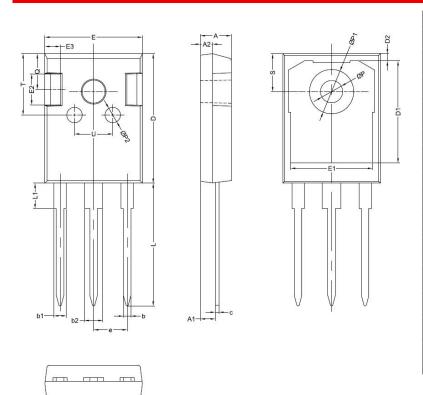
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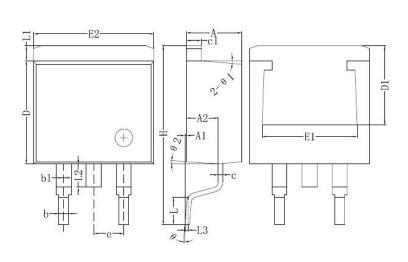


# **Mechanical Dimensions TO-247AD**



SYMBOL	Millimeters			
STWIBOL	MIN.	TYP.	MAX.	
Α	4.80		5.20	
A1	2.00		2.75	
A2	1.90		2.10	
b	1.00		1.40	
b1	1.80		2.40	
b2	2.80		3.40	
С	0.40		0.75	
D	19.80		21.20	
D1		16.55		
D2		1.20		
D1 D2 E	15.20		16.00	
E1		13.30		
E2		5.00		
E3		2.50		
е	5.20		5.70	
L	13.90		20.70	
L1	3.70		4.30	
Р	3.50		3.70	
P1	7.1		7.40	
P2		2.50		
Q		5.80		
P2 Q S T	6.05		6.25	
T		10.00		
U		6.20		

# Mechanical Dimensions D<sup>2</sup>PAK(TO-263-2)



Symbol	Dimensions in millimeters		
<b>- - - - - - - - - -</b>	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
e	2.54	BSC	
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

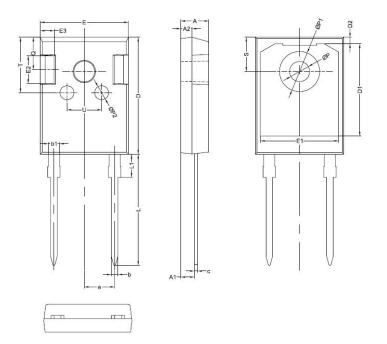
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# **Mechanical Dimensions TO-247AC**



0)/4501	Millimeters				
SYMBOL	MIN.	TYP.	MAX.		
Α	4.80	5.00	5.20		
A1	2.20	2.41	2.61		
A2	1.90	2.00	2.10		
b	1.10	1.20	1.35		
b1	1.80	2.00	2.20		
С	0.50	0.60	0.75		
D	20.30	21.00	21.20		
D1		16.58			
D2 E		1.17			
E	15.60	15.80	16.00		
E1		14.02			
E2		5.00			
E3		2.50			
е		5.44			
L	19.42	19.92	20.42		
L1		4.13			
Р	3.50	3.60	3.70		
P1	7.1	7.19	7.40		
P2		2.50			
Q		5.80			
S	6.05	6.15	6.25		
Т		10.00			
U		6.20			







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